

BIPOLAR TRANSISTOR, PNP, -300V, Collector Emitter Voltage $V_{(br)ceo}$:300V, Power Dissipation P_d :20W, Collector Current:500mA, Current Gain h_{FE} :240hFE

Manufacturers	ON Semiconductor, LLC
Package/Case	TO-126
Product Type	Transistors
RoHS	Pb-free Halide free
Lifecycle	



Images are for reference only

Please submit RFQ for MJE350G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

The PNP Bipolar Power Transistor is designed for use in line-operated applications such as low power, line-operated series pass and switching regulators requiring PNP capability.

Features

High Collector-Emitter Sustaining Voltage - = 1.0 mAdc

Excellent DC Current Gain - = 50 mAdc

Pb-Free Package is Available

Application

ONSEMI

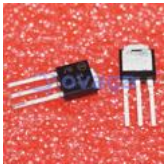


Related Products



[MJE172](#)

ON Semiconductor, LLC
TO-126



[MJD44H11-1G](#)

ON Semiconductor, LLC
TO-251



[MJ802G](#)

ON Semiconductor, LLC
TO-204-2



[MJH6287](#)

ON Semiconductor, LLC
TO-247



[MJD42CT4G](#)

ON Semiconductor, LLC
SOT25



[MJL21195G](#)

ON Semiconductor, LLC
TO-3PL



[MJ4502G](#)

ON Semiconductor, LLC
TO-204-2 (TO-3)



[MJE5852](#)

ON Semiconductor, LLC
TO-220